

Silicon Diode

1N3957GP

1000V / 1A

DATASHEET

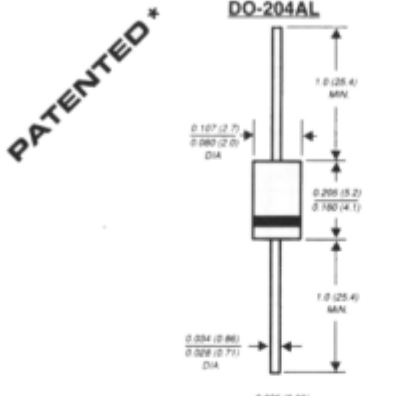
OEM – General Semiconductor

Source: General Semiconductor Databook 1998

1N3611GP THRU 1N3614GP AND 1N3957GP

GLASS PASSIVATED JUNCTION RECTIFIER

Reverse Voltage - 200 to 1000 Volts Forward Current - 1.0 Ampere



NOTE: Lead diameter is 0.028 (0.66) for suffix "C" part numbers
0.029 (0.736)

Dimensions in inches and (millimeters)

* Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306



FEATURES

- ♦ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ♦ High temperature metallurgically bonded construction
- ♦ Capable of meeting environmental standards of MIL-S-19500
- ♦ Glass passivated cavity-free junction
- ♦ 1.0 Ampere operation at $T_A=75^\circ\text{C}$ with no thermal runaway
- ♦ Typical I_R less than $0.1\mu\text{A}$
- ♦ High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, $0.375"$ (9.5mm) lead length, 5 lbs. (2.3kg) tension

MECHANICAL DATA

Case: JEDEC DO-204AL molded plastic over glass body
Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 ounce, 0.3 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	1N 3611GP	1N 3612GP	1N 3613GP	1N 3614GP	1N 3957GP	UNITS
* Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1000	Volts
* Maximum RMS voltage	V_{RMS}	140	280	420	560	700	Volts
* Maximum DC blocking voltage	V_{DC}	200	400	600	800	1000	Amps
* Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{(AV)}$	1.0					Amps
* Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30.0					Amps
Maximum instantaneous forward voltage at 1.0A	V_F	1.0					Volts
* Maximum DC reverse current at rated DC blocking voltage	I_R	1.0 300.0					μA
Typical reverse recovery time (NOTE 1)	t_{rr}	2.0					μs
Typical junction capacitance (NOTE 2)	C_J	8.0					pF
Typical thermal resistance (NOTE 3)	$R_{\theta JA}$ $R_{\theta JL}$	55.0 25.0					$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175					$^\circ\text{C}$

NOTES:

(1) Reverse recovery test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $t_r=0.25\mu\text{s}$

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

(3) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5mm) lead length, P.C.B. mounted

* JEDEC registered values

RATINGS AND CHARACTERISTIC CURVES 1N3611GP THRU 1N3614GP AND 1N3957GP

